



PATENT  
Attorney's Docket No. 3521.150

ART UNIT: 2813

EXAMINER: David I. Hogans

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: )  
CINDY SEIBEL et. al )  
Serial No.: 09/941,817 )  
Filed: Aug. 29, 2001 )

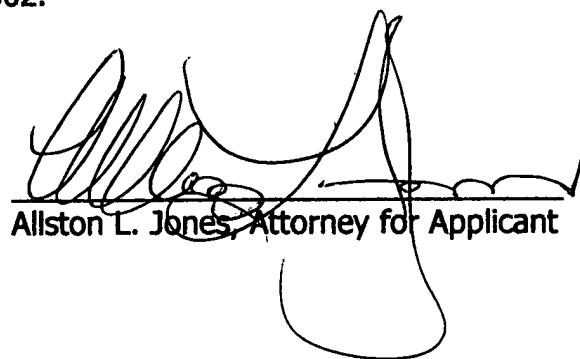
RESPONSE TO EXAMINER'S  
FIRST ACTION AND  
AMENDMENT A

For: **METHOD FOR SEMICONDUCTOR GATE DOPING**

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EXPRESS MAIL CERTIFICATE

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Allston L. Jones, Attorney for Applicant

Dear Sir:

The following Amendment and Response is being submitted in response to the



Attorney's Docket No. 3521.115

RE-PATENT  
FILED

SEP 23 2002

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AMENDMENT A DETAILS

For: **METHOD FOR SEMICONDUCTOR GATE DOPING**

In the Specification:

Page 1, line 19, delete "or" and insert – of –;

Page 5, line 23, delete first occurrence of "a";

Page 8, line 24, delete first occurrence of "a";